

# isc N-Channel MOSFET Transistor

2SK3818L

#### **FEATURES**

- Drain Current : I<sub>D</sub>= 74A@ T<sub>C</sub>=25 ℃
- Drain Source Voltage
  - : V<sub>DSS</sub>= 60V(Min)
- Static Drain-Source On-Resistance
  - :  $R_{DS(on)}$  = 13m  $\Omega$  (Max) @  $V_{GS}$ = 10V
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### **DESCRIPTION**

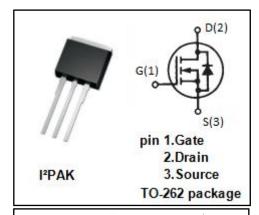
 motor drive, DC-DC converter, power switch and solenoid drive.

### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	60	V
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±20	V
I <sub>D</sub>	Drain Current-Continuous	74	А
І <sub>ОМ</sub>	Drain Current-Single Pluse	296	А
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃	75	W
TJ	Max. Operating Junction Temperature	-55~150	$^{\circ}$
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	1.67	°C/W



E/4

	MM		
DIM	MIN	MAX	
Α	4. 37	4.77	
A1	1. 22	1.42	
A2	2.47	2.87	
b	0.7	0.97	
b2	1.17	1.42	
С	0.28	0.53	
D	23. 2	24. 02	
D1	8.38	8.9	
D2	6	1	
E	9.9	10.39	
E4	7.3	1	
E	2. 54BSC		
G	1. 25	1.5	
H2	/	1. 31	
L	13.34	14. 1	
L1	3. 3	4.06	
L3	0.95	1, 15	

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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 1.0mA	60		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> = 1.0mA	1.2	2.6	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 37A V <sub>GS</sub> = 4.0V; I <sub>D</sub> = 37A		13 18	m Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±16V;V <sub>DS</sub> =0		±10	uA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 60V; V <sub>GS</sub> = 0		1.0	uA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 74A; V <sub>GS</sub> = 0		1.5	V

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